

MGA-632P8

Low Noise, High Linearity Active Bias Low Noise Amplifier



Data Sheet

Description

Avago Technologies' MGA-632P8 is an economical, easy-to-use GaAs MMIC Low Noise Amplifier (LNA) with active bias. The LNA has low noise with excellent input return loss and high linearity achieved through the use of Avago Technologies' proprietary 0.5um GaAs Enhancement-mode pHEMT process. The LNA has an extra feature that allows a designer to adjust supply current and gain externally. Due to the high isolation between the input and output, gain can be adjusted independently through a resistor in series with a blocking capacitor from the output pin to FB1 pin, without affecting the noise figure. It is housed in a miniature 2.0 x 2.0 x 0.75mm³ 8-pin Thin Small Leadless Package (TSLP) package. The compact footprint and low profile coupled with low noise, high gain, excellent input return loss and high linearity make the MGA-632P8 an ideal choice as an LNA for cellular infrastructure for GSM, CDMA, W-CDMA and TD-SCDMA applications.

It is designed for optimum use between 1.4GHz to 3.8GHz. For optimum performance at lower frequency from 400MHz to 1.5GHz, the MGA-631P8 is recommended. Both MGA-631P8 and MGA-632P8 share the same package and pinout.

Pin Configuration and Package Marking

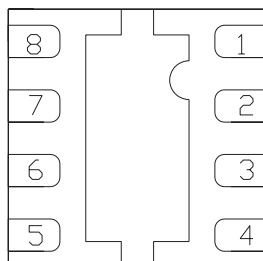
2.0 x 2.0 x 0.75 mm³ 8-lead TSLP



Top View

Note:

Package marking provides orientation and identification
"G2" is Device Code
"X" is month code



Bottom View

Note:

Pin 1 : not used	Pin 5 : FB1
Pin 2 : RFin	Pin 6 : not used
Pin 3 : RF ground	Pin 7 : RFout
Pin 4 : Vbias	Pin 8 : Gnd

Features

- Low noise figure
- Good input return loss
- High linearity performance
- High Isolation
- Externally adjustable supply current, 40-80mA
- Externally adjustable gain, 15-20dB
- GaAs E-pHEMT Technology^[1]
- Low cost small package size: 2.0x2.0x0.75 mm³
- Excellent uniformity in product specifications

Specifications

1.95GHz; 4V, 57mA (typ)

- 17.6 dB Gain
- 0.62 dB Noise Figure
- -22.7 dB S11
- -40.5 dB S12
- 33.9 dBm Output IP3
- 19.2 dBm Output Power at 1dB gain compression

Applications

- Low noise amplifier for cellular infrastructure for GSM, CDMA, W-CDMA and TD-SCDMA.
- Other ultra low noise applications.

Note:

1. Enhancement mode technology employs positive Vbias, thereby eliminating the need of negative gate voltage associated with conventional depletion mode devices.



Attention: Observe precautions for handling electrostatic sensitive devices.

ESD Machine Model = 50 V

ESD Human Body Model = 200 V

Refer to Avago Application Note A004R:

Electrostatic Discharge, Damage and Control.

MGA-632P8 Absolute Maximum Rating [1]

Symbol	Parameter	Units	Absolute Max.
Vd	Device Supply Voltage	V	5.5
P _{in,max} (ON)	CW RF Input Power (Vd = 4.0V, Vbias=4.0V)	dBm	20
P _{in,max} (OFF)	CW RF Input Power (Vd=4.0V, Vbias=0V)	dBm	25
P _{diss}	Total Power Dissipation [2]	W	0.55
T _j	Junction Temperature	°C	150
T _{STG}	Storage Temperature	°C	-65 to 150

Thermal Resistance [3] (Vd = 4.0V, Vbias=4.0V), $\theta_{jc} = 47\text{ }^{\circ}\text{C/W}$

Notes:

1. Operation of this device in excess of any of these limits may cause permanent damage.
2. Board temperature T_B is 25 °C. Derate 21.2mW/ °C for T_B>124 °C.
3. Thermal resistance measured using Infra-Red Microscopy Technique.

Product Consistency Distribution Charts [4]

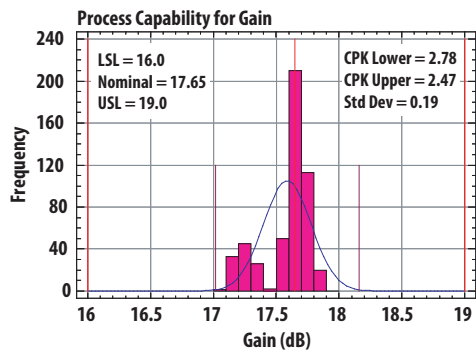


Figure 1. Gain distribution at 57mA

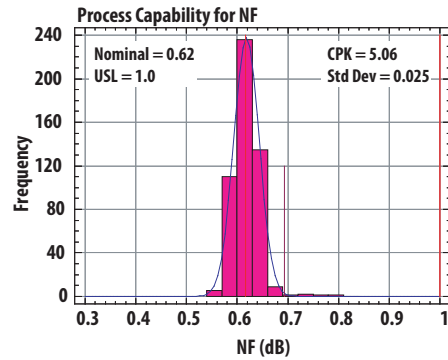


Figure 2. NF distribution at 57mA

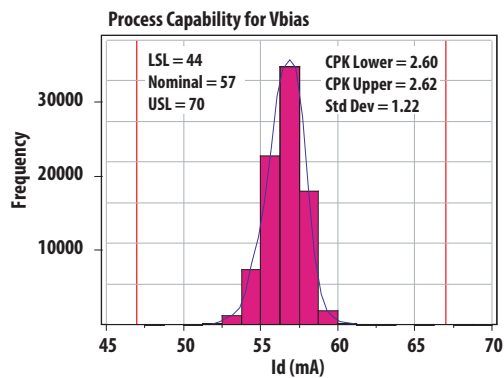


Figure 3. Id distribution at 57mA

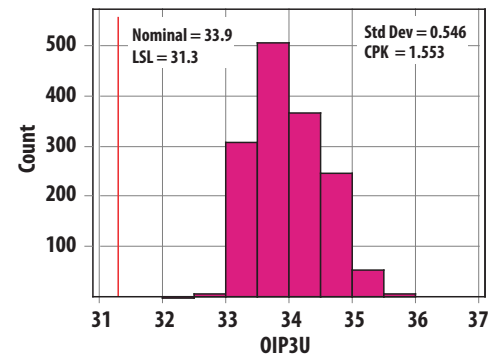


Figure4. OIP3U distribution at 57mA.

Note:

4. Distribution data sample size is 500 samples taken from 3 different wafer lots. Future wafer allocated to this product may have nominal values anywhere between the upper and lower limits. Circuit losses have been de-embedded from actual measurements.

Electrical Specifications [1, 2]

$T_A = 25^\circ\text{C}$, $V_d = 4\text{V}$ @ 57mA, $R_1 = 300\Omega$ unless otherwise specified.

Symbol	Parameter and Test Condition		Units	Min.	Typ.	Max.
Id	Operational Current	$V_{bias} = 4.0\text{V}$	mA	44	57	70
Gain	Freq=1.75 GHz	Associated Gain	dB	16.0	18.3	19.0
	Freq=1.85 GHz				17.9	
	Freq=1.95 GHz				17.6	
OIP3	Freq=1.75 GHz	Output Third Order Intercept Point (2-tone @ $F_{RF} \pm 2.5\text{MHz}$, $P_{in} = -20\text{dBm}$)	dBm	31.3	34.7	
	Freq=1.85 GHz				34.3	
	Freq=1.95 GHz				33.9	
NF _{50Ω}	Freq=1.75 GHz	Noise Figure in 50Ω system	dB		0.59	1.0
	Freq=1.85 GHz				0.59	
	Freq=1.95 GHz				0.62	
OP1dB	Freq=1.75 GHz	Output Power at 1dB Gain Compression	dBm		18.8	
	Freq=1.85 GHz				19.2	
	Freq=1.95 GHz				19.2	
IRL	Freq=1.75 GHz	Input Return Loss	dB		-32.1	
	Freq=1.85 GHz				-27.6	
	Freq=1.95 GHz				-22.7	
ORL	Freq=1.75 GHz	Output Return Loss	dB		-12.2	
	Freq=1.85 GHz				-13.6	
	Freq=1.95 GHz				-13.9	
S12	Freq=1.75 GHz	Reverse Isolation	dB		-40.2	
	Freq=1.85 GHz				-40.4	
	Freq=1.95 GHz				-40.5	

Notes:

- Measurements obtained using demo board described in Figure 31 and Table 1, List 1. Input and output board losses have been de-embedded.
- Guaranteed specifications are 100% tested in production test circuit.

Typical Electrical Specifications at 2.6GHz [1]

$T_A = 25^\circ\text{C}$, $V_d = 4\text{V}$ @ 57mA, $R_1 = 300\Omega$ unless otherwise specified.

Symbol	Parameter and Test Condition		Units	Typ.
Gain	Freq=2.6GHz	Associated Gain	dB	15.3
OIP3	Freq=2.6GHz	Output Third Order Intercept Point (2-tone @ $F_{RF} \pm 2.5\text{MHz}$, $P_{in} = -20\text{dBm}$)	dBm	33.4
NF _{50Ω}	Freq=2.6GHz	Noise Figure in 50Ω system	dB	0.97
OP1dB	Freq=2.6GHz	Output Power at 1dB Gain Compression	dBm	18.5
IRL	Freq=2.6GHz	Input Return Loss	dB	-33.4
ORL	Freq=2.6GHz	Output Return Loss	dB	-8.7
S12	Freq=2.6GHz	Reverse Isolation	dB	-39.8

Notes:

- Measurements obtained using demo board described in Figure 31 and Table 1, List 3. Input and output board losses have been de-embedded.

Typical Electrical Specifications at 3.5GHz [1]

T_A = 25 °C, V_d = 4V @ 57mA, R₁ = 300ohm unless otherwise specified.

Symbol	Parameter and Test Condition		Units	Typ.
Gain	Freq=3.5GHz	Associated Gain	dB	12.0
OIP3	Freq=3.5GHz	Output Third Order Intercept Point (2-tone @ F _{RF} +/- 2.5MHz, Pin = -20dBm)	dBm	32.0
NF _{50Ω}	Freq=3.5GHz	Noise Figure in 50Ω system	dB	1.25
OP1dB	Freq=3.5GHz	Output Power at 1dB Gain Compression	dBm	18.4
IRL	Freq=3.5GHz	Input Return Loss	dB	-14.9
ORL	Freq=3.5GHz	Output Return Loss	dB	-11.5
S12	Freq=3.5GHz	Reverse Isolation	dB	-40.5

Notes:

1. Measurements obtained using demo board described in Figure 31 and Table 1, List 4. Input and output board losses have been de-embedded.

MGA-632P8 Typical Performance [1]

$T_A = +25^\circ\text{C}$, $V_d = 4\text{V}$, $I_d = 57\text{mA}$, $R_1 = 300\Omega$ unless stated otherwise.

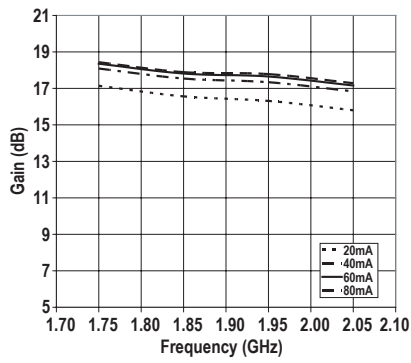


Figure 5. Gain Vs Frequency and I_d

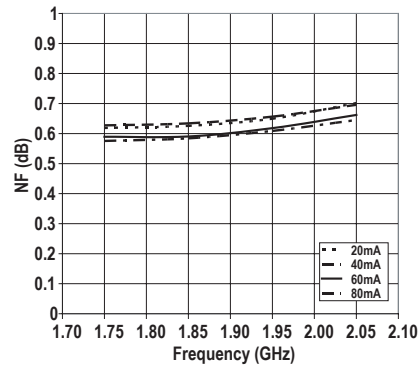


Figure 6. NF Vs Frequency and I_d

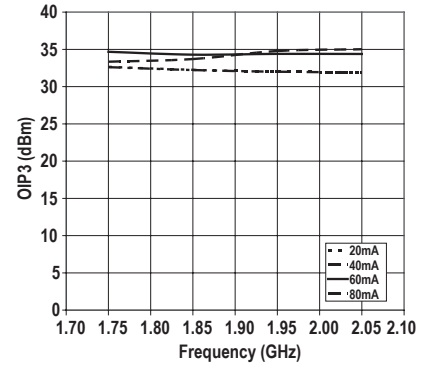


Figure 7. OIP3 Vs Frequency and I_d

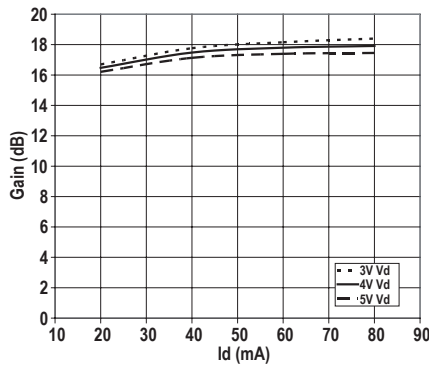


Figure 8. Gain Vs I_d and V_d

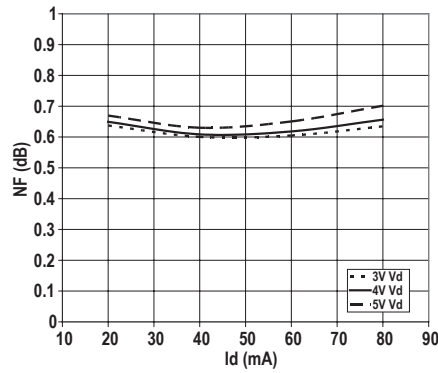


Figure 9. NF Vs I_d and V_d

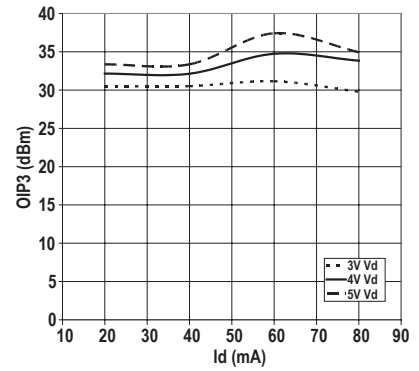


Figure 10. OIP3 Vs I_d and V_d

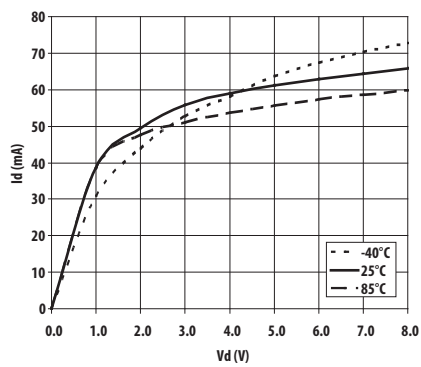


Figure 11. I_d Vs V_d and Temperature

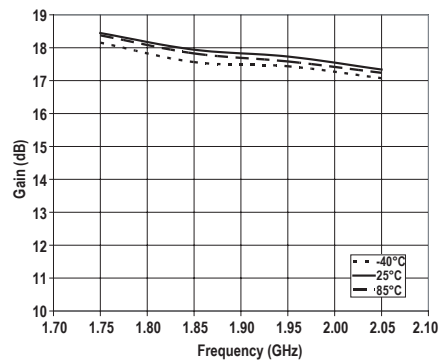


Figure 12. Gain Vs Frequency and Temperature

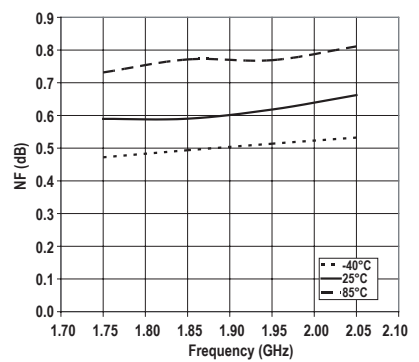


Figure 13. NF Vs Frequency and Temperature

Notes:

1. Measurements obtained using demo board described in Figure 28 and Table 1, List 1.

MGA-632P8 Typical Performance [1]

$T_A = +25^\circ\text{C}$, $V_d = 4\text{V}$, $I_d = 57\text{mA}$, $R_1 = 300\text{ohm}$ unless stated otherwise.

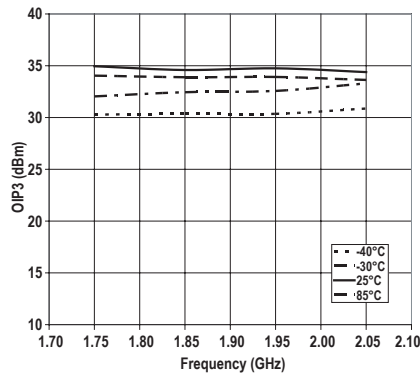


Figure 14. OIP3 vs Frequency and Temperature

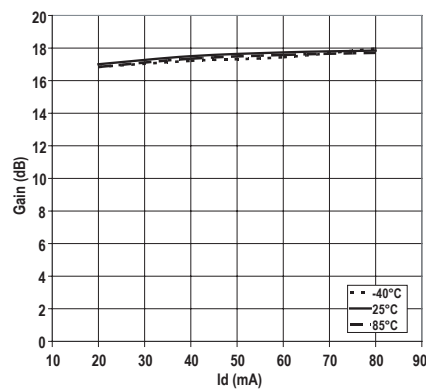


Figure 15. Gain vs Id and Temperature

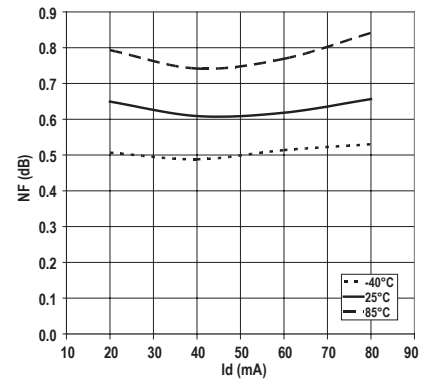


Figure 16. NF vs Id and Temperature

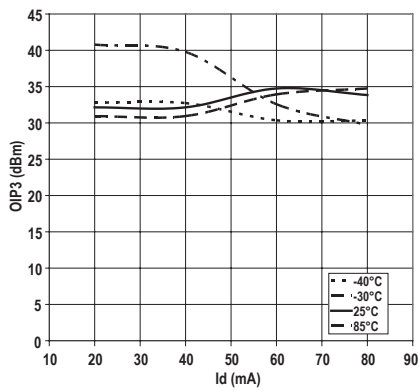


Figure 17. OIP3 vs Id and Temperature

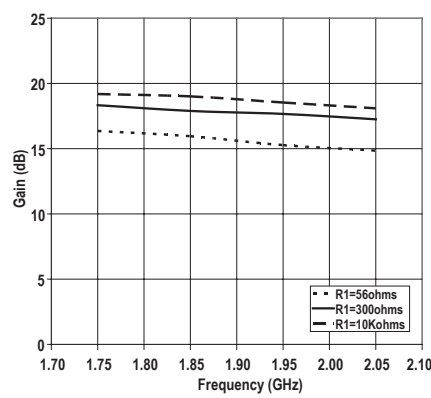


Figure 17. Gain vs Frequency and R1

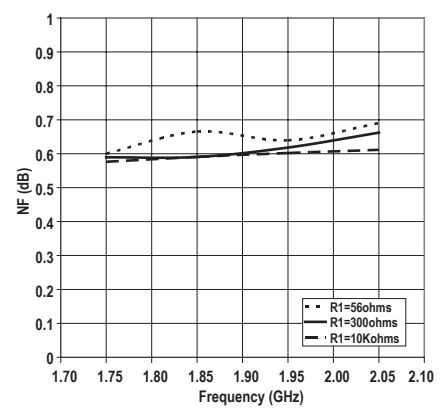


Figure 19. NF vs Frequency and R1

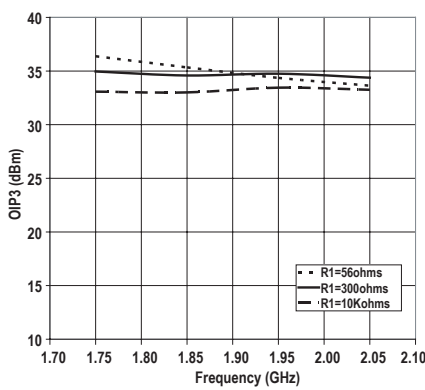


Figure 20. OIP3 vs Frequency and R1

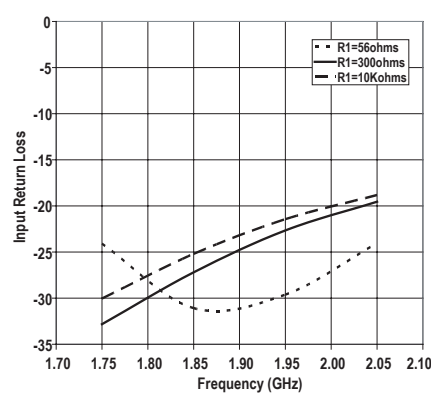


Figure 21. Input Return Loss vs Frequency and R1

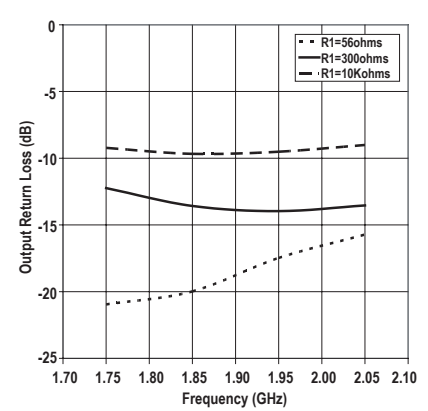


Figure 22. Output Return Loss vs Frequency and R1

Notes:

1. Measurements obtained using demo board described in Figure 28 and Table 1, List 1.

MGA-632P8 Typical Performance for 1.5 GHz Matching [1]

$T_A = +25^\circ\text{C}$, $V_d = 4\text{V}$, $I_d = 57\text{mA}$

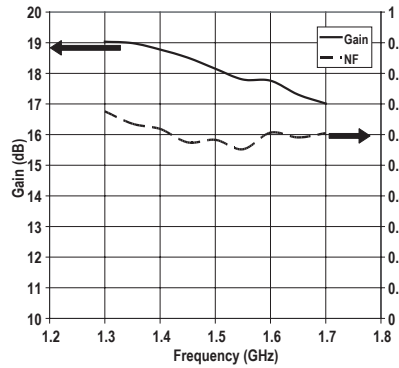


Figure 23. Gain and NF Vs Frequency

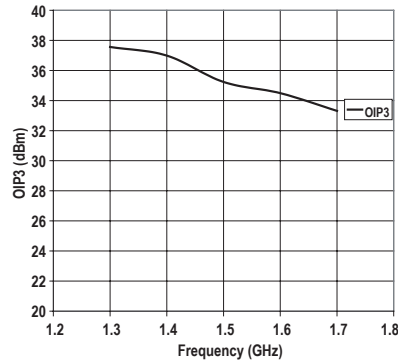


Figure 24. OIP3 vs Frequency

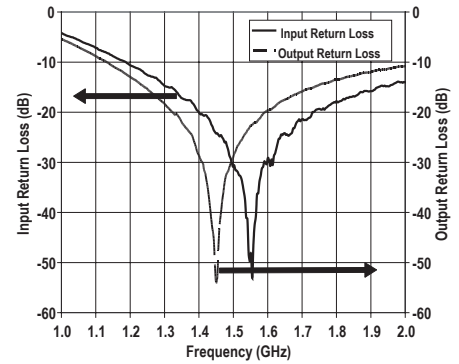


Figure 25. Input and output Return Loss vs Frequency

MGA-632P8 Typical Performance for 2.6 GHz Matching [2]

$T_A = +25^\circ\text{C}$, $V_d = 4\text{V}$, $I_d = 57\text{mA}$

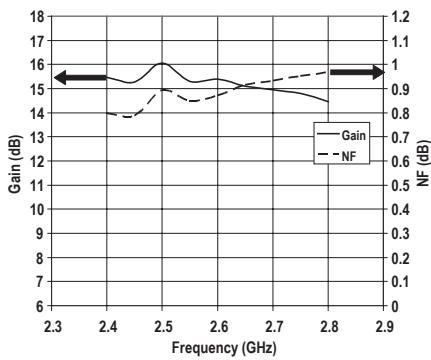


Figure 26. Gain and NF vs Frequency

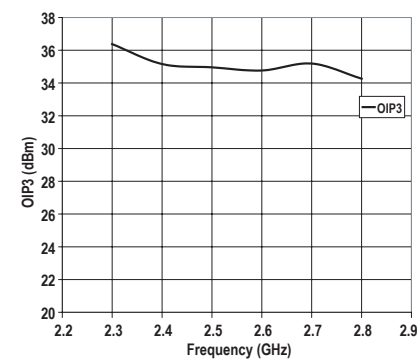


Figure 27. OIP3 vs Frequency

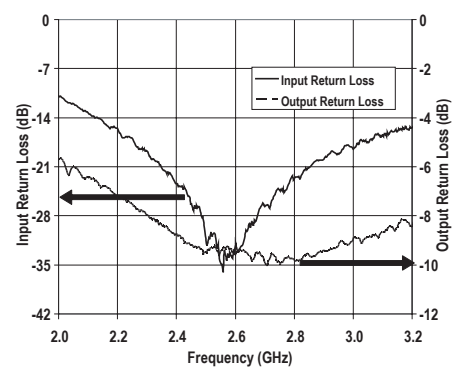


Figure 28. Input and output Return Loss vs Frequency

MGA-632P8 Typical Performance for 3.5GHz Matching [3]

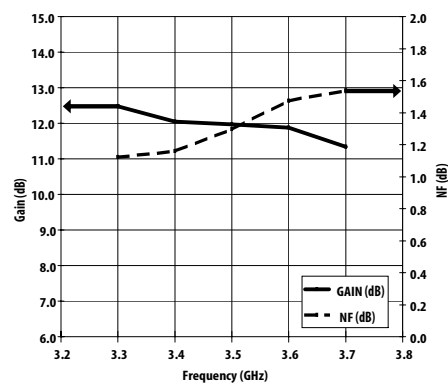


Figure 29. Gain and NF vs Frequency

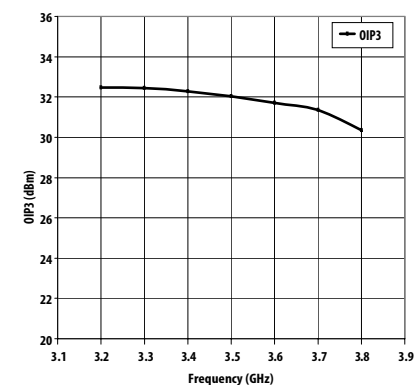


Figure 30. OIP3 vs Frequency

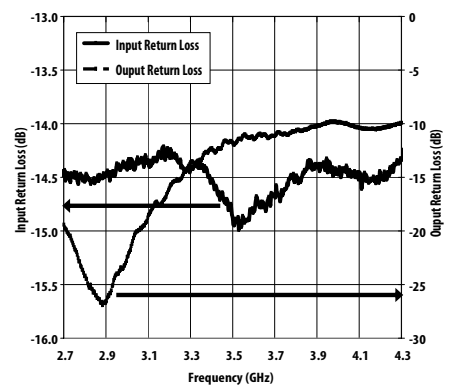


Figure 31. Input and Output Return Loss vs Frequency

Notes:

1. For Figure 22, 23 and 24, measurements obtained using demo board described in Figure 32 and Table 1, List 2.
2. For Figure 25, 26 and 27, measurements obtained using demo board described in Figure 32 and Table 1, List 3.
3. For figure 28, 29 and 30, measurements obtained using demo board described in Figure 32 and Table 1, List 4.

Demo Board Layout

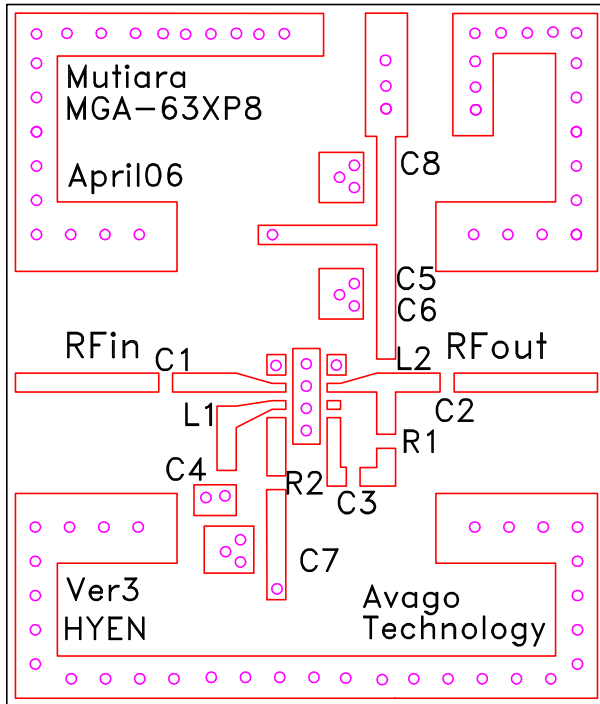


Figure 32. Demo Board Layout Diagram

- Recommended PCB material is 10 mils Rogers RO4350.
- Suggested component values may vary according to layout and PCB material.

Demo Board Schematic for Table 1

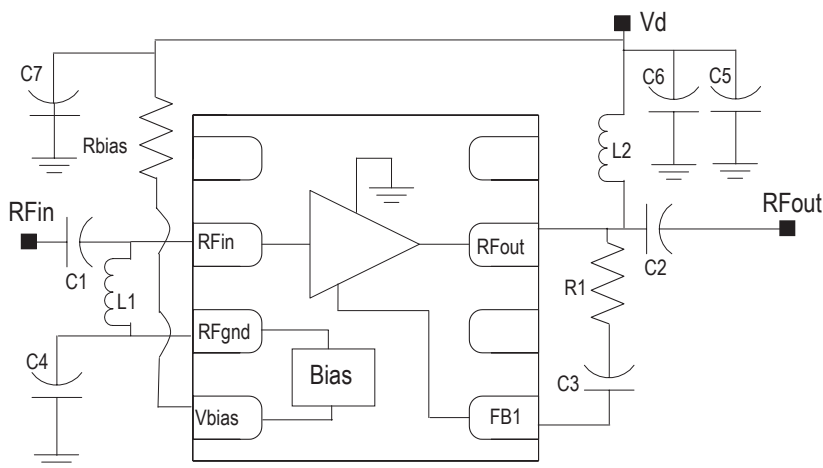


Figure 33. Demo Board Schematic. This demo board is used for the measurement.

Table 1

- List 1 – Demo Board Component values for Demo board Schematic of Fig. 29.
These component values are used when measuring electrical specifications and plots of Fig. 4 to Fig. 21.
- List 2 – Demo Board Component values for Demo board Schematic of Fig. 29.
These component values are used when measuring plots of Fig. 22 to Fig. 24.
- List 3 – Demo Board Component values for Demo board Schematic of Fig. 29.
These component values are used when measuring plots of Fig. 25 to Fig. 27.
- List 4 - Demo Board Component Values for Demo board Schematic of Fig 29.
These component Values are used when measuring plots of Fig. 28 to Fig. 30.

Part	Size	List 1	(1.95 GHz Matching)	List 2	(1.5 GHz Matching)
L1	0402	3.6nH	(Coilcraft 0402CS-3N6XJBW)	3.9nH	(Coilcraft 0402CS-3N9XJBW)
L2	0402	2.2nH	(Coilcraft 0402CS-2N2XJBW)	3.3nH	(Coilcraft 0402CS-3N3XJBW)
C1	0402	2.2pF	(Rohm MCH155A022JK)	2.7pF	(Rohm MCH155027JK)
C2	0402	2.4pF	(Rohm MCH155A024CK)	3.0pF	(Rohm MCH155A030CK)
C3	0402	1.2pF	(Rohm MCH155A1R2CK)	1.2pF	(Rohm MCH155A1R2CK)
C4	0402	100pF	(Rohm MCH155A101JK)	100pF	(Rohm MCH155A101JK)
C5	0402	0.1uF	(Kyocera CM05X5R104K10AH)	0.1uF	(Kyocera CM05X5R104K10AH)
C6	0402	9pF	(Rohm MCH155A090DK)	9pF	(Rohm MCH155A090DK)
C7	0402	0.1uF	(Kyocera CM05X5R104K10AH)	0.1uF	(Kyocera CM05X5R104K10AH)
R1	0402	300Ω	(Rohm MCR01MZSJ301)	91Ω	(Rohm MCR01MZSJ910)
Rias	0402	620Ω	(Rohm MCR01MZSJ621)	620Ω	(Rohm MCR01MZSJ621)

Part	Size	List 3	(2.6GHz Matching)	List 4	(3.5GHz Matching)
L1	0402	1.5nH	(Toko LL1005-FHL1N5S)	3.9nH	(Toko LL005-FHL3N9S)
L2	0402	1.0nH	(Toko LL1005-FHL1N0S)	1.2nH	(Toko LL005-FHL1N2S)
C1	0402	2.0pF	(Rohm MCH155A2R0CK)	4.3pF	(Murata MCH155A4R3JK)
C2	0402	100pF	(Rohm MCH155A101JK)	4.3pF	(Murata MCH155A4R3JK)
C3	0402	5.6pF	(Rohm MCH155A5R6CK)	1.2pF	(Murata GRM1555C1H1R2BZ01D)
C4	0402	100pF	(Rohm MCH155A101JK)	100pF	(Murata GRM1555C1H101JD01E)
C5	0402	0.1uF	(Kyocera CM05X5R104K10AH)	0.1uF	(Kyocera CM05X5R04K10AH)
C6	0402	0.5pF	(Rohm MCH155A0R5CK)	4.3pF	(Murata MCH155A4R3JK)
C7	0402	0.1uF	(Kyocera CM05X5R104K10AH)	0.1uF	(Kyocera CM05X5R04K0AH)
R1	0402	1.5kW	(Rohm MCR01MZSJ152)	150Ω	(Rohm MCR01MZSJ151)
Rias	0402	620Ω	(Rohm MCR01MZSJ621)	620Ω	(Rohm MCR01MZSJ621)

Load pull test set up

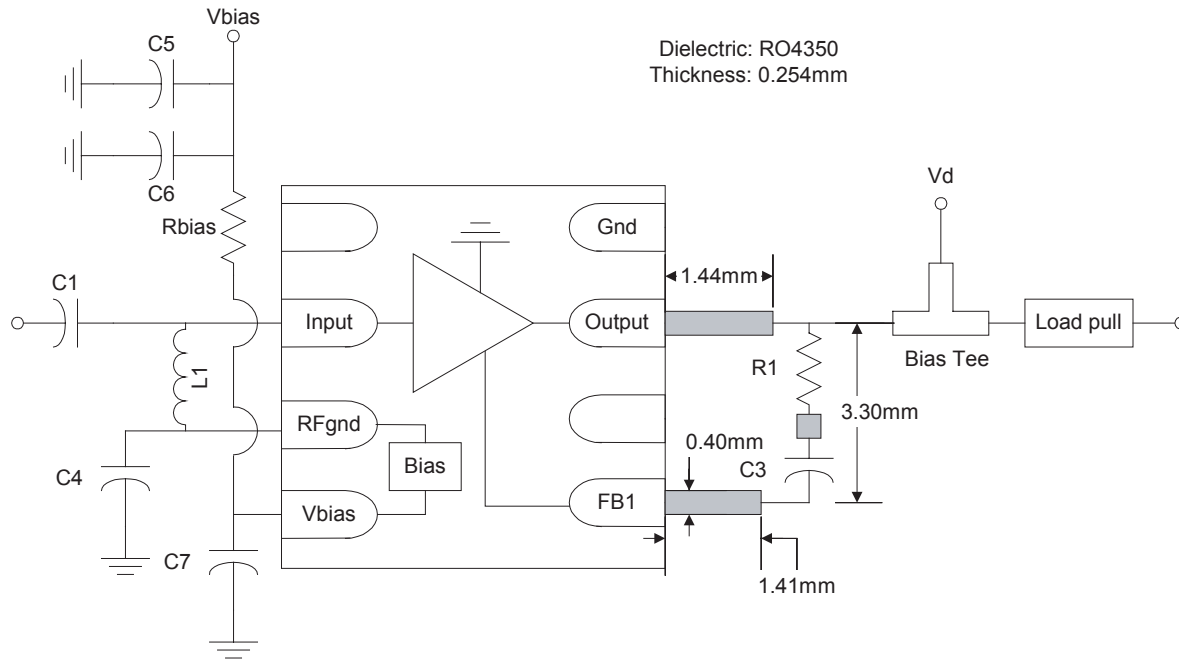


Figure 34. Test setup for load pull data

The input port is matched for good NF and IRL. Because of the high reverse isolation, any change on the output port has a minimum change on the input port. Therefore, only the output port is tuned for the maximum OIP3. R1 is varied for different level of gain. Test condition for the OIP3: -20dBm at 1.95GHz $\pm$ 5MHz.

Measured results

Test condition: 4V/57mA, 1.95GHz

Refer to Table 1, List 1 for SMT component value and description, unless otherwise stated.

Resistor, R1	Γ	OIP3 (max)
160ohm	$0.48 < 91.4^\circ$	+39.3dBm
56ohm	$0.61 < 134.2^\circ$	+38.1dBm
10kohm	$0.40 < 150^\circ$	+38.5dBm

Fixed Load Pull

Freq = 1.9500 GHz

Ip3 max = 39.26 dBm
at 0.4827< 91.40
10 contours, 1.00 dBm step
(30.00 to 39.00 dBm)

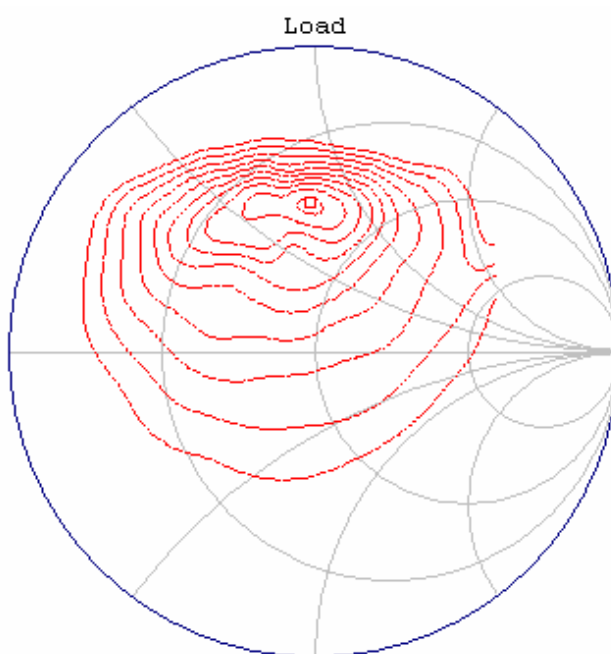


Figure 35. Load pull contour plot for R1=160ohm

Fixed Load Pull
Freq = 1.9500 GHz

Ip3 max = 38.08 dBm
 at 0.6108< 134.21
10 contours, 1.00 dBm step
(29.00 to 38.00 dBm)

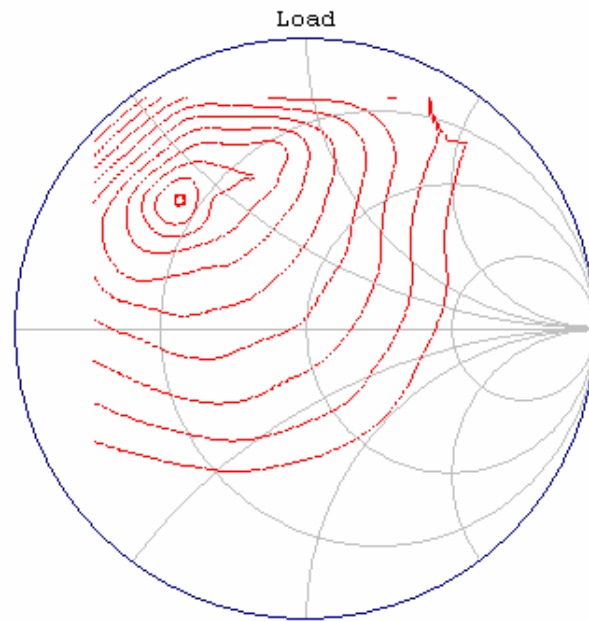


Figure 36. Load pull contour plot for R1=56ohm

Fixed Load Pull
Freq = 1.9500 GHz

Ip3 max = 38.50 dBm
 at 0.4018< 149.92
10 contours, 1.00 dBm step
(29.00 to 38.00 dBm)

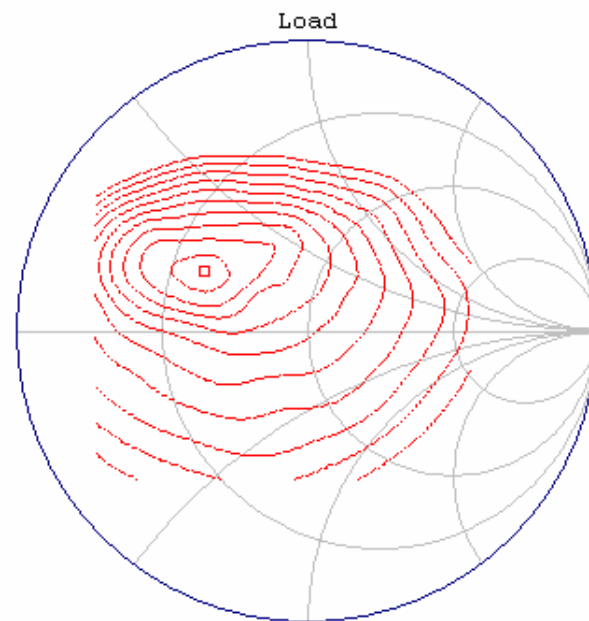
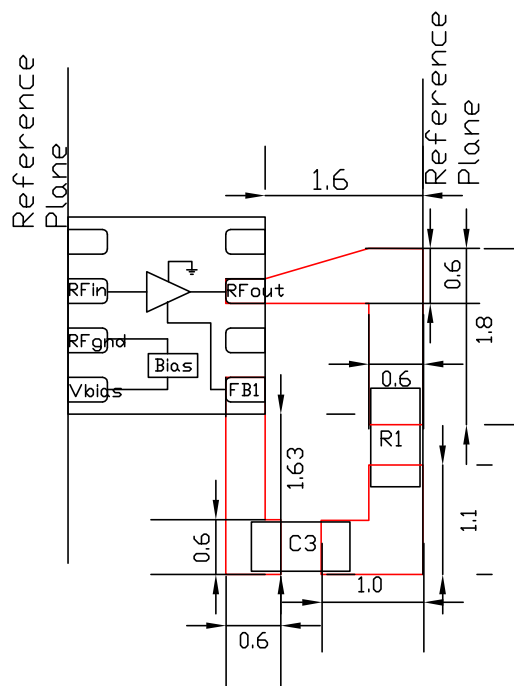


Figure 37. Load pull contour plot for R1=10kohm

MGA-632P8 Scattering Parameter and Noise Parameter Test Setup



Note: All dimensions are in mm.
PCB material is 10 mils Rogers R04350.

Figure 38. Test Setup for S & Noise Parameters data, C3=1.2pF (Rohm MCH155A1R2CK)

Typical Noise Parameter, $V_d=4V$, $I_d=57mA$, applicable to any R1 due to high reverse isolation

Freq (GHz)	FMIN (dB)	GAMMA Mag	OPT Ang	Rn/50
0.9	0.41	0.31	78	0.10
1.9	0.55	0.27	92	0.06
2.0	0.54	0.27	93	0.07
2.4	0.66	0.22	98	0.07
3.0	0.77	0.28	101	0.08

Notes:

1. Fmin values at 2 GHz and higher are based on measurements while the Fmins below 2 GHz have been extrapolated. The Fmin values are based on a set of 16 noise figure measurements made at 16 different impedances using an ATN NP5 test system. From these measurements a true Fmin is calculated.
2. S and noise parameters are measured on PCB. The PCB material is 10 mils Roger RO4350. Figure 34 shows the input and output reference plane.

MGA632P8 Typical Scattering Parameters, Vd=4V, Id=57mA, R1=56ohm

Freq	S11		S21		S12		S22	
(GHz)	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
0.1	0.96	-10.5	25.83	165.6	0.006	89.2	0.68	-13.4
0.5	0.72	-39.5	17.06	132.7	0.006	60.2	0.53	-47.7
0.9	0.53	-51.9	11.58	118.1	0.009	64.7	0.49	-71.7
1.0	0.50	-53.5	10.34	115.9	0.009	63.4	0.49	-77.6
1.5	0.40	-57.1	6.80	110.6	0.011	69.6	0.47	-101.7
1.9	0.36	-57.2	5.11	112.8	0.012	68.8	0.47	-118.0
2.0	0.36	-57.5	4.74	112.5	0.012	73.8	0.46	-120.3
2.5	0.35	-58.3	4.00	117.2	0.011	72.9	0.46	-135.6
3.0	0.34	-59.7	3.23	122.9	0.010	82.5	0.45	-145.9
3.5	0.34	-61.5	2.99	128.8	0.008	83.3	0.47	-154.8
4.0	0.33	-63.8	2.71	133.3	0.007	93.7	0.48	-163.6
5.0	0.30	-71.9	2.61	136.0	0.001	-174.8	0.53	172.7
6.0	0.26	-86.6	2.48	136.1	0.008	-59.8	0.54	142.1
7.0	0.26	-111.8	2.52	134.6	0.026	-50.6	0.48	97.6
8.0	0.34	-156.0	2.96	115.6	0.071	-59.7	0.45	9.7

MGA632P8 Typical Scattering Parameters, Vd=4V, Id=57mA, R1=91ohm

Freq	S11		S21		S12		S22	
(GHz)	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
0.1	0.97	-10.0	25.88	165.6	0.003	44.1	0.68	-12.0
0.5	0.73	-39.0	17.05	133.4	0.006	66.2	0.51	-46.3
0.9	0.53	-51.2	11.64	119.9	0.008	58.0	0.47	-67.8
1.0	0.50	-52.8	10.45	117.8	0.009	57.1	0.46	-73.5
1.5	0.41	-56.3	7.08	113.1	0.010	63.8	0.46	-94.5
1.9	0.37	-57.7	5.43	114.3	0.011	67.7	0.48	-109.1
2.0	0.37	-58.0	5.11	113.4	0.010	71.1	0.48	-111.5
2.5	0.35	-59.6	4.35	116.7	0.009	78.2	0.48	-126.8
3.0	0.35	-60.8	3.46	120.0	0.008	80.5	0.50	-138.5
3.5	0.34	-62.6	3.14	124.5	0.007	98.7	0.52	-150.4
4.0	0.33	-64.5	2.74	128.8	0.006	112.6	0.54	-162.2
5.0	0.30	-71.8	2.55	133.4	0.001	-179.0	0.56	171.7
6.0	0.26	-86.1	2.43	134.9	0.008	-62.6	0.54	141.3
7.0	0.26	-111.9	2.49	133.9	0.026	-48.8	0.48	97.9
8.0	0.34	-156.2	2.94	114.6	0.070	-59.2	0.44	9.7

Notes:

1. S-parameters are measured on PCB. The PCB material is 10 mils Roger RO4350. Figure 34 shows the input and output reference plane.

MGA632P8 Typical Scattering Parameters, Vd=4V, Id=57mA, R1=300ohm

Freq	S11		S21		S12		S22	
(GHz)	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
0.1	0.96	-10.6	25.70	165.8	0.008	151.3	0.68	-14.0
0.5	0.73	-37.7	17.33	136.8	0.005	57.6	0.49	-36.0
1.0	0.52	-51.7	11.36	121.3	0.006	52.9	0.51	-57.7
1.5	0.42	-57.6	8.01	114.2	0.006	67.2	0.53	-79.5
1.9	0.38	-59.6	6.17	113.2	0.007	78.1	0.57	-95.3
2.0	0.38	-60.3	5.80	111.5	0.007	77.2	0.57	-99.3
2.5	0.36	-62.3	4.93	113.3	0.006	97.2	0.59	-117.3
3.0	0.34	-63.0	3.80	114.4	0.007	106.7	0.61	-132.1
3.5	0.33	-64.1	3.33	118.7	0.006	123.0	0.62	-146.4
4.0	0.32	-65.2	2.81	122.6	0.006	135.6	0.63	-159.8
5.0	0.29	-71.6	2.54	127.6	0.004	-166.1	0.62	172.5
6.0	0.26	-86.0	2.39	130.8	0.008	-69.5	0.57	142.0
7.0	0.26	-113.2	2.45	130.3	0.026	-50.4	0.50	99.7
8.0	0.34	-158.3	2.90	111.0	0.068	-58.2	0.41	13.1

MGA632P8 Typical Scattering Parameters, Vd=4V, Id=57mA, R1=1.5kohm

Freq	S11		S21		S12		S22	
(GHz)	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
0.1	0.96	-10.0	25.56	167.3	0.005	69.2	0.66	-8.6
0.5	0.75	-36.8	18.56	137.9	0.003	59.6	0.58	-29.4
0.9	0.57	-50.3	13.44	123.6	0.004	64.3	0.60	-48.4
1.0	0.54	-52.4	12.15	120.6	0.004	58.9	0.60	-54.5
1.5	0.43	-58.5	8.48	112.8	0.006	82.2	0.62	-77.1
2.0	0.38	-61.2	6.08	109.6	0.007	98.5	0.64	-97.4
2.5	0.35	-62.9	5.15	111.5	0.006	103.4	0.66	-115.6
3.0	0.34	-63.6	3.92	112.3	0.006	121.8	0.65	-130.5
3.5	0.33	-64.5	3.43	116.8	0.007	130.7	0.66	-145.0
4.0	0.32	-65.6	2.87	120.9	0.006	147.1	0.66	-158.5
5.0	0.28	-71.9	2.57	126.4	0.004	-149.2	0.64	173.5
6.0	0.26	-85.9	2.42	129.4	0.009	-61.3	0.59	143.3
7.0	0.26	-111.4	2.51	129.6	0.026	-50.4	0.50	101.3
8.0	0.34	-159.0	3.01	109.6	0.069	-57.4	0.40	12.4

Notes:

1. S-parameters are measured on PCB. The PCB material is 10 mils Roger RO4350. Figure 34 shows the input and output reference plane.

MGA632P8 Typical Scattering Parameters, Vd=4V, Id=57mA, R1=10kohm

Freq (GHz)	S11		S21		S12		S22	
	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
0.1	0.96	-9.9	26.06	168.1	0.005	-41.8	0.72	-5.1
0.5	0.75	-36.8	18.98	137.5	0.003	67.3	0.62	-29.7
0.9	0.57	-50.7	13.68	123.2	0.004	67.8	0.61	-48.3
1.0	0.54	-52.8	12.37	120.0	0.004	72.2	0.61	-54.6
1.5	0.43	-59.0	8.60	112.2	0.006	86.7	0.63	-77.1
1.9	0.39	-61.6	6.54	110.8	0.006	91.9	0.66	-92.7
2.0	0.38	-61.8	6.12	108.8	0.006	95.4	0.66	-97.1
2.5	0.36	-63.7	5.20	111.0	0.006	105.8	0.66	-115.3
3.0	0.34	-64.0	3.92	111.8	0.006	118.7	0.66	-130.1
3.5	0.33	-65.2	3.45	116.0	0.006	137.8	0.67	-144.6
4.0	0.32	-65.8	2.90	120.3	0.005	143.2	0.67	-158.1
5.0	0.29	-71.9	2.61	125.8	0.003	-148.6	0.65	173.9
6.0	0.26	-86.0	2.44	129.1	0.008	-71.3	0.58	144.2
7.0	0.26	-113.0	2.53	128.8	0.026	-50.6	0.49	101.8
8.0	0.35	-159.1	3.07	109.0	0.067	-58.6	0.39	11.5

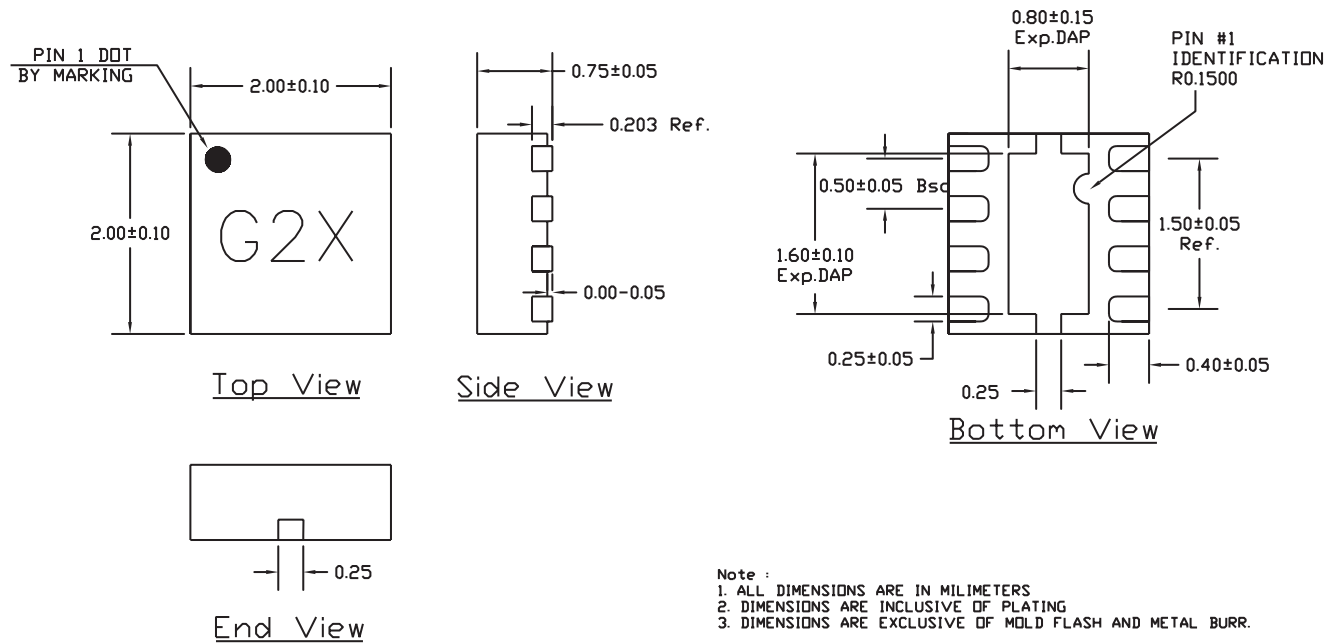
Notes:

1. S-parameters are measured on PCB. The PCB material is 10 mils Roger RO4350. Figure 34 shows the input and output reference plane.

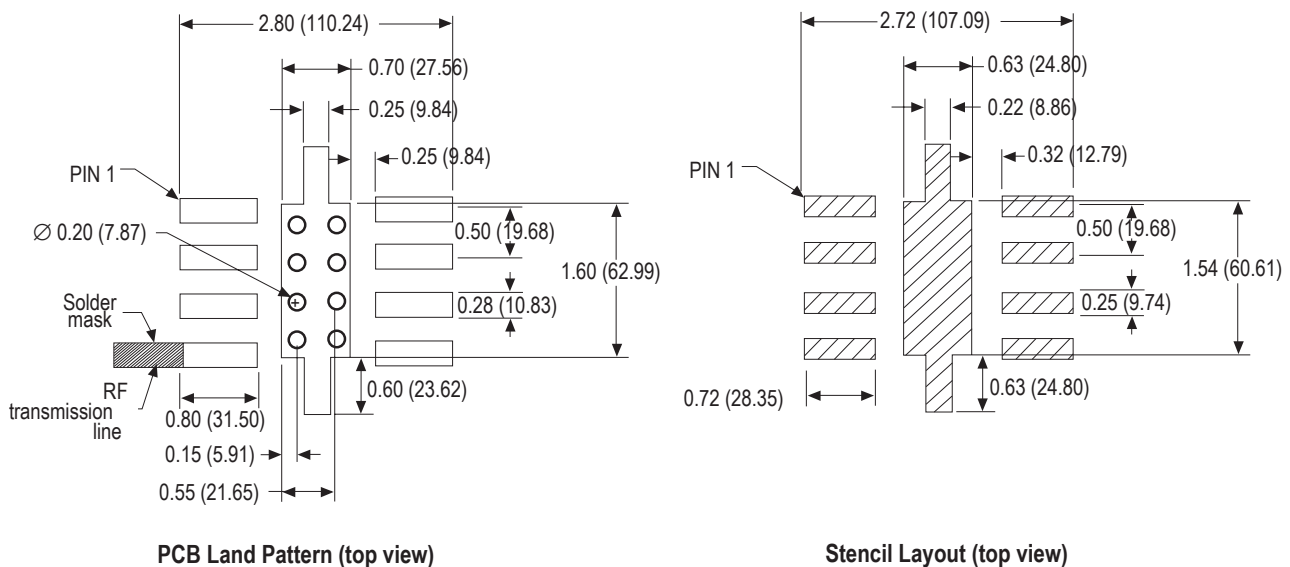
Ordering Information

Part Number	No. of Devices	Container
MGA-632P8-TR1G	3000	7" Reel
MGA-632P8-TR2G	10000	13" Reel
MGA-632P8-BLKG	100	antistatic bag

TSLP2X2 Package Dimension

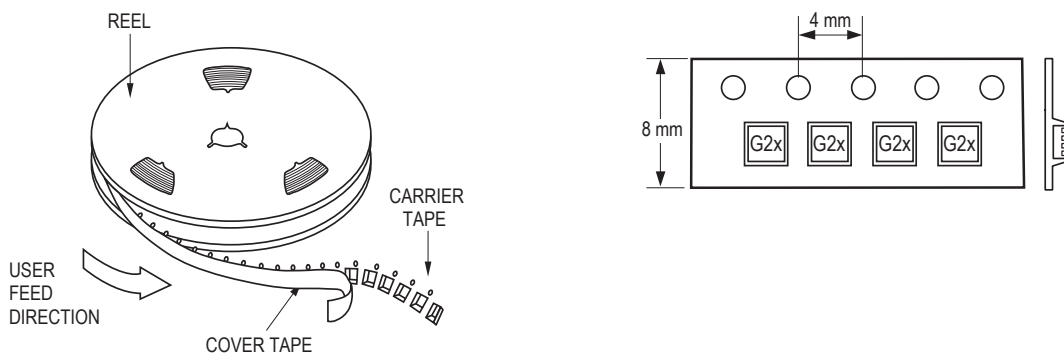


PCB Land Pattern and Stencil Design

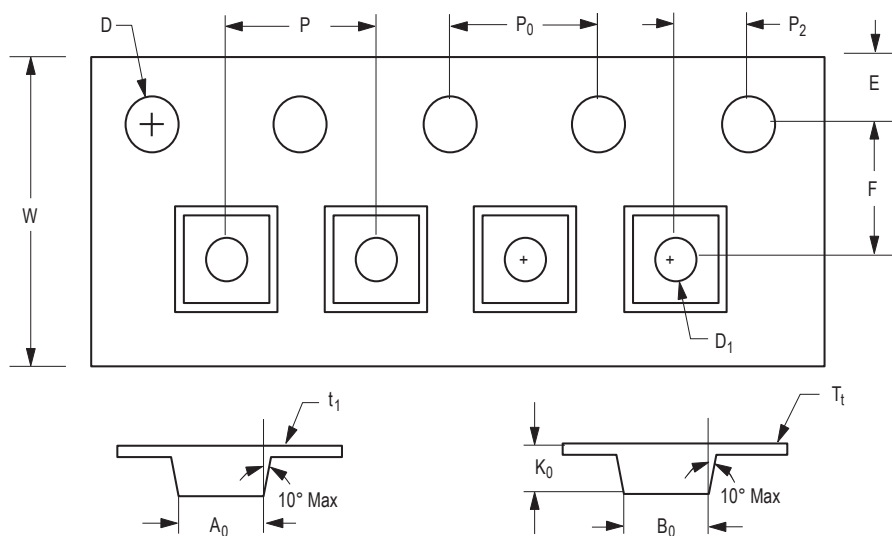


All dimensions are in millimeters (mils)
Note: 1 mil = 1/1000 inch

Device Orientation



Tape Dimensions



DESCRIPTION		SYMBOL	SIZE (mm)	SIZE (inches)
CAVITY	LENGTH	A_0	2.30 ± 0.05	0.091 ± 0.004
	WIDTH	B_0	2.30 ± 0.05	0.091 ± 0.004
	DEPTH	K_0	1.00 ± 0.05	0.039 ± 0.002
	PITCH	P	4.00 ± 0.10	0.157 ± 0.004
	BOTTOM HOLE DIAMETER	D_1	1.00 ± 0.25	0.039 ± 0.002
PERFORATION	DIAMETER	D	1.50 ± 0.10	0.060 ± 0.004
	PITCH	P_0	4.00 ± 0.10	0.157 ± 0.004
	POSITION	E	1.75 ± 0.10	0.069 ± 0.004
CARRIER TAPE	WIDTH	W	8.00 ± 0.30	0.315 ± 0.012
	THICKNESS	t_1	0.254 ± 0.02	0.010 ± 0.0008
COVER TAPE	WIDTH	C	5.4 ± 0.10	0.205 ± 0.004
	TAPE THICKNESS	T_t	0.062 ± 0.001	0.0025 ± 0.0004
DISTANCE	CAVITY TO PERFORATION (WIDTH DIRECTION)	F	3.50 ± 0.05	0.138 ± 0.002
	CAVITY TO PERFORATION (LENGTH DIRECTION)	P_2	2.00 ± 0.05	0.079 ± 0.002

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